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DMP3028LK3-13

Diodes Incorporated

MOSFET P-Ch Enh Mode -30V Low Rdson -20Vgss

Any questions, please feel free to contact us. info@kaimte.com





DMP3028LK3

30V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(on)} | Ι _D T _C = +25°C |
|----------------------|------------------------------|--|
| -30V | $25m\Omega @ V_{GS} = -10V$ | -27A |
| | $38m\Omega @ V_{GS} = -4.5V$ | -22A |

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- DC-DC Converters
- Power Management Functions

Features

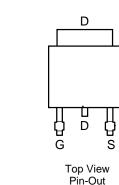
- 100% Unclamped Inductive Switch (UIS) Test In Production
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

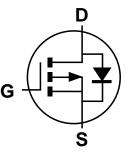
Mechanical Data

- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.33 grams (Approximate)



Top View





Equivalent Circuit

Ordering Information (Notes 4)

| Product | Case | Packaging |
|---------------|-------|-------------------|
| DMP3028LK3-13 | TO252 | 2,500/Tape & Reel |

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

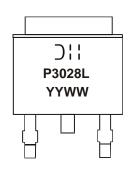
and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html .

Marking Information

Notes:



>:! = Manufacturer's Marking P3028L= Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 14 = 2014) WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units | | |
|--|-----------------|---|------------------|-------------|----|
| Drain-Source Voltage | | | V _{DSS} | -30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 6))/ 40)/ | Steady State | $T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$ | ID | -27 -22 | A |
| Continuous Drain Current (Note 6) $V_{GS} = -10V$ | t<10s | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | Ι _D | -11 -8.6 | A |
| Maximum Body Diode Continuous Current | | | ls | -2.5 | A |
| Pulsed Drain Current (10µs pulse, duty cycle = 1%) | | | I _{DM} | -40 | A |
| Avalanche Current (Note 7) L = 0.1mH | | | las | -22 | A |
| Avalanche Energy (Note 7) L = 0.1mH | | | Eas | 24 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units | |
|--|------------------------|----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | T _A = +25°C | Р | 1.6 | W |
| | T _A = +70°C | PD | 1.0 | |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady state | Devi | 77 | °C/W |
| | t<10s | R _{0JA} | 34 | C/W |
| Total Power Dissipation (Note 6) | T _A = +25°C | PD | 2.8 | W |
| | T _A = +70°C | PD | 1.8 | |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady state | Devi | 45 | °C/W |
| merinal Resistance, sunction to Ambient (Note 0) | t<10s | R _{0JA} | 29 | |
| Thermal Resistance, Junction to Case (Note 6) | | $R_{\theta JC}$ | 4.5 | |
| Operating and Storage Temperature Range | | T _{J,} T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|------|------|-------|--|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -30 | _ | — | V | $V_{GS} = 0V, I_D = -250\mu A$ | |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | _ | _ | -1 | μA | $V_{DS} = -30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | _ | _ | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | · | |
| Gate Threshold Voltage | V _{GS(th)} | -1 | — | -2.4 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ | |
| Static Drain-Source On-Resistance | Deserve | | 20 | 25 | mΩ | $V_{GS} = -10V, I_D = -7A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 29 | 38 | 11152 | $V_{GS} = -4.5V, I_D = -6.2A$ | |
| Diode Forward Voltage | V _{SD} | _ | -0.7 | -1.2 | V | $V_{GS} = 0V, I_{S} = -2.1A$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | · | |
| Input Capacitance | Ciss | _ | 1241 | _ | pF | | |
| Output Capacitance | C _{oss} | _ | 147 | _ | pF | − V _{DS} = -15V, V _{GS} = 0V − f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | _ | 110 | _ | pF | | |
| Gate Resistance | R _G | _ | 15 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = -10V) | Qg | _ | 22 | _ | nC | | |
| Total Gate Charge (V _{GS} = -4.5V) | Qg | _ | 11 | _ | nC | Vps = -15V. ID = -7A | |
| Gate-Source Charge | Q _{gs} | _ | 3.5 | — | nC | -VDS = -15V, ID = -7A | |
| Gate-Drain Charge | Q _{gd} | _ | 4.7 | _ | nC | | |
| Turn-On Delay Time | t _{D(on)} | _ | 9.7 | | ns | | |
| Turn-On Rise Time | tr | _ | 17.1 | | ns | $V_{GS} = -10V, V_{DD} = -15V,$ | |
| Turn-Off Delay Time | t _{D(off)} | _ | 60.5 | | ns | - R _{GEN} = 6Ω - I _D = -7Α | |
| Turn-Off Fall Time | t _f | _ | 40.4 | _ | ns | | |

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. 7. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep $T_J = 25^{\circ}$ C. 8. Short duration pulse test used to minimize self-heating effect. Notes:

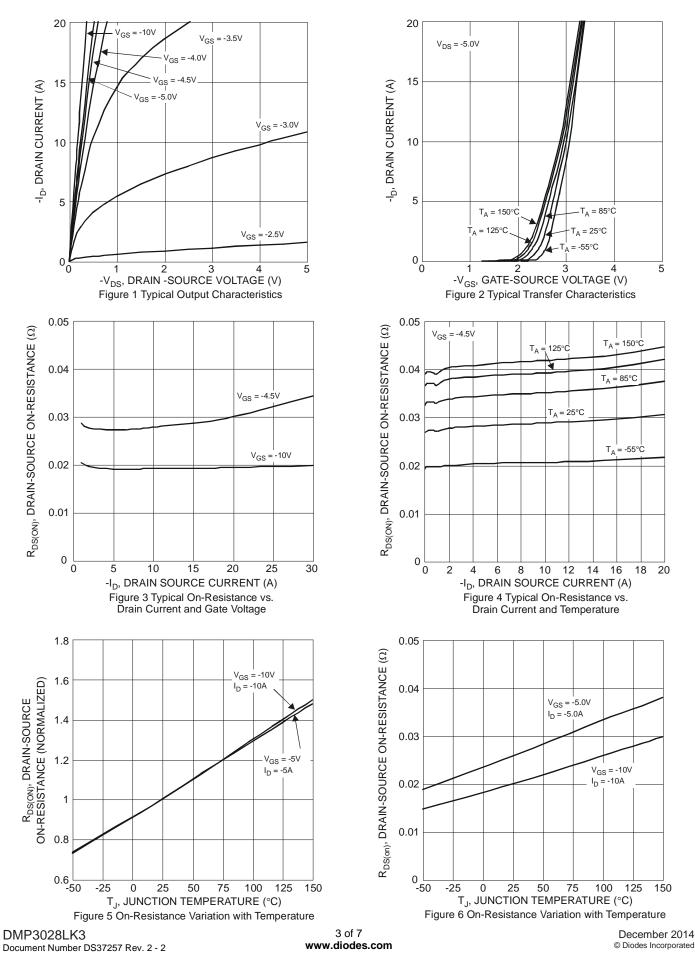
9. Guaranteed by design. Not subject to product testing.

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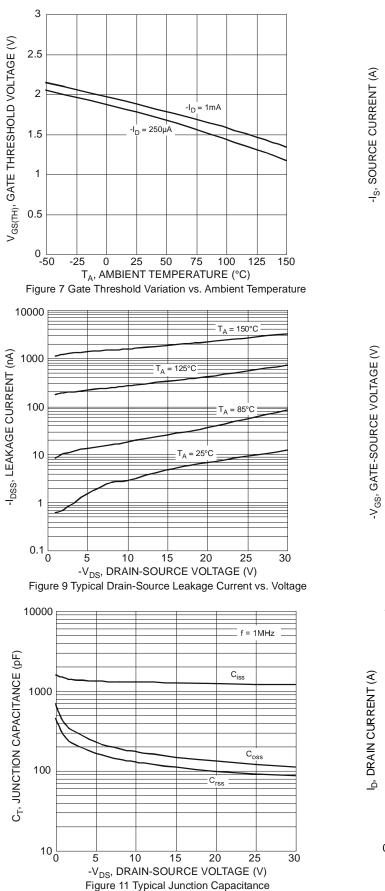
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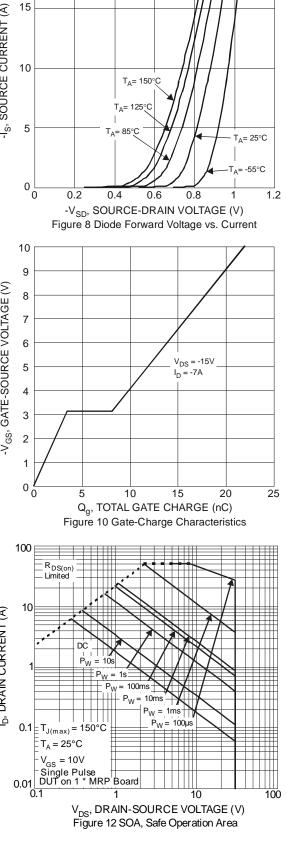




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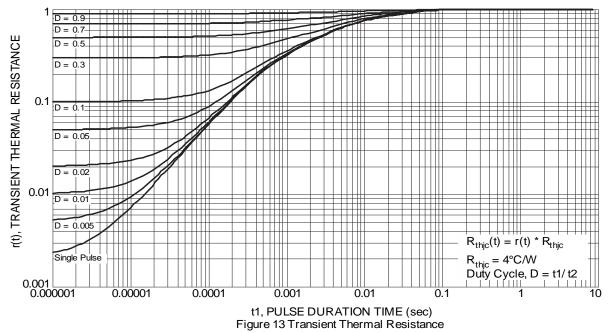




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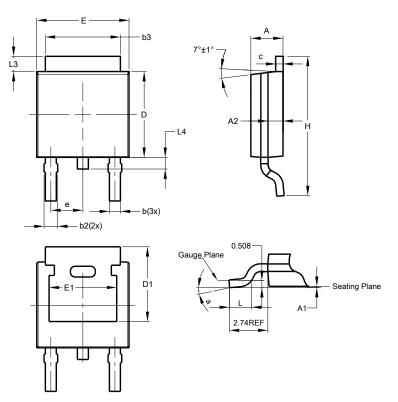






Package Outline Dimensions

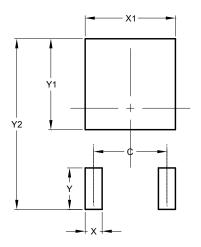
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| TO252 (DPAK) | | | | | | |
|----------------------|------|-------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 2.19 | 2.39 | 2.29 | | | |
| A1 | 0.00 | 0.13 | 0.08 | | | |
| A2 | 0.97 | 1.17 | 1.07 | | | |
| b | 0.64 | 0.88 | 0.783 | | | |
| b2 | 0.76 | 1.14 | 0.95 | | | |
| b3 | 5.21 | 5.46 | 5.33 | | | |
| С | 0.45 | 0.58 | 0.531 | | | |
| D | 6.00 | 6.20 | 6.10 | | | |
| D1 | 5.21 | - | - | | | |
| е | - | - | 2.286 | | | |
| Ε | 6.45 | 6.70 | 6.58 | | | |
| E1 | 4.32 | - | - | | | |
| Н | 9.40 | 10.41 | 9.91 | | | |
| L | 1.40 | 1.78 | 1.59 | | | |
| L3 | 0.88 | 1.27 | 1.08 | | | |
| L4 | 0.64 | 1.02 | 0.83 | | | |
| а | 0° | 10° | - | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 4.572 |
| Х | 1.060 |
| X1 | 5.632 |
| Y | 2.600 |
| Y1 | 5.700 |
| Y2 | 10.700 |



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